

High Speed 8-Bit TTL A/D Converter

AD9012

FEATURES

100 MSPS Encode Rate Very Low Input Capacitance—16 pF Low Power—1 W TTL Compatible Outputs MIL-STD-883 Compliant Versions Available

APPLICATIONS

Radar Guidance Digital Oscilloscopes/ATE Equipment Laser/Radar Warning Receivers Digital Radio Electronic Warfare (ECM, ECCM, ESM) Communication/Signal Intelligence

GENERAL DESCRIPTION

The AD9012 is an 8-bit, ultrahigh speed, analog-to-digital converter. The AD9012 is fabricated in an advanced bipolar process that allows operation at sampling rates up to one hundred megasamples/second. Functionally, the AD9012 is comprised of 256 parallel comparator stages whose outputs are decoded to drive the TTL compatible output latches.

The exceptionally wide large-signal analog input bandwidth of 160 MHz is due to an innovative comparator design and very close attention to device layout considerations. The wide input bandwidth of the AD9012 allows very accurate acquisition of high speed pulse inputs without an external track-and-hold. The comparator output decoding scheme minimizes false codes, which is critical to high speed linearity.

The AD9012 is available in two grades: one with 0.5 LSB linearity and one with 0.75 LSB linearity. Both versions are offered in

FUNCTIONAL BLOCK DIAGRAM



an industrial grade, -25° C to $+85^{\circ}$ C, packaged in a 28-lead DIP and a 28-lead JLCC. The military temperature range devices, -55° C to $+125^{\circ}$ C, are available in ceramic DIP and LCC packages and are compliant to MIL-STD-883 Class B.

The AD9012 is available in versions compliant with MIL-STD-883. Refer to the Analog Devices Military Products Databook or current AD9012/883B data sheet for detailed specifications.

REV. C

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$\label{eq:additional} \begin{array}{l} \textbf{AD9012-SPECIFICATIONS} \\ \textbf{ELECTRICAL CHARACTERISTICS} & (+V_{s}=+5.0 \ \text{V}; -V_{s}=-5.2 \ \text{V}; \ \text{Differential Reference Voltage} = 2.0 \ \text{V}; \ \text{unless otherwise noted}) \end{array}$

Parameter	Temp	Test Level	AI Min)9012A(Тур	Q/AJ Max	AI Min	99012ВС Тур	Q/BJ Max	AD Min	9012SC Typ)/SE Max	AD Min	9012TC Typ	Q/TE Max	Units
RESOLUTION			8			8			8			8			Bits
DC ACCURACY Differential Linearity Integral Linearity No Missing Codes	+25°C Full +25°C Full Full	I VI I VI VI	GUA	0.6 0.6 RANTE	0.75 1.0 1.0 1.2 EED	GU	0.4 0.4 ARANT	0.5 0.75 0.5 1.2 YEED	GU	0.6 0.6 ARAN	0.75 1.0 1.0 1.2 FEED	GU	0.4 0.4 JARAN	0.5 0.75 0.5 1.2 TEED	LSB LSB LSB LSB
INITIAL OFFSET ERROR Top of Reference Ladder Bottom of Reference Ladder Offset Drift Coefficient	+25°C Full +25°C Full Full	I VI I VI V		7 6 25	15 18 10 13		7 6 25	15 18 10 13		7 6 25	15 18 10 13		7 6 25	15 18 10 13	$\begin{array}{c} mV\\ mV\\ mV\\ mV\\ \mu V/^{\circ}C \end{array}$
ANALOG INPUT Input Bias Current ¹ Input Resistance Input Capacitance Large Signal Bandwidth ² Analog Input Slew Rate ³	+25°C Full +25°C +25°C +25°C +25°C	I VI I III V V	100	60 200 16 160 440	100 200 18	100	60 200 16 160 440	100 200 18	100	60 200 16 160 440	100 200 18	100	60 200 16 160 440	100 200 18	μΑ μΑ kΩ pF MHz V/μs
REFERENCE INPUT Reference Ladder Resistance Ladder Temperature Coefficient Reference Input Bandwidth	+25°C +25°C	VI V V	40	80 0.25 10	110	40	80 0.25 10	110	40	80 0.25 10	110	40	80 0.25 10	110	Ω Ω/°C MHz
$\hline \hline DYNAMIC PERFORMANCE \\ Conversion Rate \\ Aperture Delay \\ Aperture Uncertainty (Jitter) \\ Output Delay (t_{PD})^{4,5} \\ Transient Response6 \\ Overvoltage Recovery Time7 \\ Output Rise Time4 \\ Output Fall Time4 \\ Output Time Skew4, 8 \\ \hline \hline \hline \end{tabular}$	+25°C +25°C +25°C +25°C +25°C +25°C +25°C +25°C +25°C +25°C	I V I V V I I I V	75 4	100 3.8 15 4.9 8 6.6 3.3 3.0	11 8.0 4.3	75 4	100 3.8 15 4.9 8 8 6.6 3.3 3.0	11 8.0 4.3	75 4	100 3.8 15 4.9 8 8 6.6 3.3 3.0	11 8.0 4.3	75 4	100 3.8 15 4.9 8 8 6.6 3.3 3.0	11 8.0 4.3	MSPS ns ps ns ns ns ns ns ns ns ns
ENCODE INPUT Logic "1" Voltage ⁴ Logic "0" Voltage ⁴ Logic "1" Current Logic "0" Current Input Capacitance Encode Pulsewidth (Low) ⁹ Encode Pulsewidth (High) ⁹	Full Full Full +25°C +25°C +25°C	VI VI VI VI I I	2.0 2.5 2.5	2.5	0.8 250 400	2.0 2.5 2.5	2.5	0.8 250 400	2.0 2.5 2.5	2.5	0.8 250 400	2.0 2.5 2.5	2.5	0.8 250 400	V V μA μA pF ns ns
OVERFLOW INHIBIT INPUT 0 V Input Current	Full	VI		200	250		200	250		200	250		200	250	μA
AC LINEARITY ¹⁰ Effective Bits ¹¹ In-Band Harmonics dc to 1.23 MHz	+25°C +25°C	V I	48	7.5 55		48	7.5 55		48	7.5 55		48	7.5 55		Bits dBc
dc to 9.3 MHz dc to 19.3 MHz Signal-to-Noise Ratio ¹² Noise Power Ratio ¹³	+25°C +25°C +25°C +25°C +25°C	V V I V	46	50 44 47.6 37		46	50 44 47.6 37		46	50 44 47.6 37		46	50 44 47.6 37		dBc dBc dBc dBc dBc
DIGITAL OUTPUT Logic "1" Voltage Logic "0" Voltage	Full Full	VI VI	2.4		0.4	2.4		0.4	2.4		0.4	2.4		0.4	V V
POWER SUPPLY ¹⁴ Positive Supply Current (+5.0 V) Supply Current (-5.2 V) Nominal Power Dissipation Reference Ladder Dissipation Power Supply Rejection Ratio ¹⁵	+25°C Full +25°C Full +25°C +25°C +25°C	I VI I VI V V I		33 152 955 44 0.85	45 48 179 191 2.5		33 152 955 44 0.85	45 48 179 191 2.5		33 152 955 44 0.8	45 48 179 191 2.5		33 152 955 44 0.8	45 48 179 191 2.5	mA mA mA mW mW mV/V

NOTES

¹Measured with Analog Input = 0 V.
²Measured by FFT analysis where fundamental is -3 dBc.
³Input slew rate derived from rise time (10% to 90%) of full-scale step input.
⁴Outputs terminated with two equivalent 'LS00 type loads. (See load circuit.)
⁵Measured from ENCODE into data out for LSB only.
⁶For full-scale step input, 8-bit accuracy is attained in specified time.
⁷Recovers to 8-bit accuracy in specified time, after 150% full-scale input overvoltage.
⁸Output time skew uncludes high-to-low and low-to-high transitions as well as bit-to-bit time skew differences.

ABSOLUTE MAXIMUM RATINGS¹

Positive Supply Voltage (+V _S)+6 V
Analog to Digital Supply Voltage Differential $(-V_S)$ 0.5 V
Negative Supply Voltage $(-V_S)$
Analog Input Voltage $\dots \dots \dots$
ENCODE Input Voltage0.5 V to +5 V
OVERFLOW INH Input Voltage5.2 V to 0 V
Reference Input Voltage $(+V_{REF}-V_{REF})^2$ 3.5 V to +0.1 V
Differential Reference Voltage2.1 V
Reference Midpoint Current ±4 mA
Digital Output Current 30 mA
Operating Temperature Range
AD9012AQ/BQ/AJ/BJ25°C to +85°C
AD9012SE/SQ/TE/TQ
Storage Temperature Range65°C to +150°C
Junction Temperature ³ +175°C
Lead Soldering Temperature (10 sec)+300°C

NOTES

¹Absolute maximum ratings are limiting values, to be applied individually, and beyond which the serviceability of the circuit may be impaired. Functional operability under any of these conditions is not necessarily implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

 $^{2}+V_{REF} \ge -V_{REF}$ under all circumstances.

 3 Maximum junction temperature (t_J max) should not exceed +175 °C for ceramic packages, and +150 °C for plastic packages:

 $\begin{aligned} t_J &= \text{PD} \ (\theta_{JA}) + t_A \\ \text{PD} \ (\theta_{JC}) + tc \end{aligned}$

where

PD = power dissipation

 θ_{JA} = thermal impedance from junction to ambient (°C/W)

 θ_{JC} = thermal impedance from junction to case (°C/W)

 $t_A =$ ambient temperature (°C)

 t_C = case temperature (°C)

typical thermal impedances are:

Ceramic DIP $\hat{\theta}_{JA} = 42^{\circ}C/W; \ \theta_{JC} = 10^{\circ}C/W$ Ceramic LCC $\theta_{JA} = 50^{\circ}C/W; \ \theta_{JC} = 15^{\circ}C/W$ JLCC $\theta_{LA} = 59^{\circ}C/W; \ \theta_{IC} = 15^{\circ}C/W.$

Recommended Operating Conditions

	Input Voltage						
Parameter	Min	Nominal	Max				
$-V_{S}$	-5.46	-5.20	-4.94				
$+V_{s}$	+4.75	5.00	+5.25				
+V _{RFF}	-V _{REF}	0.0 V	+0.1				
-V _{REF}	-2.1	-2.0	$+V_{REF}$				
Analog Input	-V _{REF}		$+V_{REF}$				

⁹ENCODE signal rise/fall times should be less than 30 ns for normal operation. ¹⁰Measured at 75 MSPS encode rate. Harmonic data based on worst case harmonics.

¹¹Analog input frequency = 1.23 MHz.

¹²RMS signal to rms noise, including harmonics with 1.23 MHz. analog input signal.

- ¹³NPR measured @ 0.5 MHz. Noise Source is 250 mW (rms) from 0.5 MHz to 8 MHz.
- $^{14}\text{Supplies}$ should remain stable within $\pm 5\%$ for normal operation.

¹⁵Measured at $-5.2 \text{ V} \pm 5\%$ and $+5.0 \text{ V} \pm 5\%$.

Specifications subject to change without notice.



Figure 1. Load Circuit

EXPLANATION OF TEST LEVELS

Test Level

- I 100% production tested.
- II 100% production tested at +25°C, and sample tested at specified temperatures. AC testing done on sample basis.
- III Sample tested only.
- IV Parameter is guaranteed by design and characterization testing.
- V Parameter is a typical value only.
- VI All devices are 100% production tested at +25°C. 100% production tested at temperature extremes for extended temperature devices; guaranteed by design and characterization testing for industrial devices.

ORDERING GUIDE

Device	Linearity	Temperature Range	Package Options*
AD9012AQ	0.75 LSB	–25°C to +85°C	Q-28
AD9012BQ	0.50 LSB	–25°C to +85°C	Q-28
AD9012AJ	0.75 LSB	–25°C to +85°C	J-28A
AD9012BJ	0.50 LSB	–25°C to +85°C	J-28A
AD9012SQ	0.75 LSB	–55°C to +125°C	Q-28
AD9012SE	0.75 LSB	–55°C to +125°C	E-28A
AD9012TQ	0.50 LSB	–55°C to +125°C	Q-28
AD9012TE	0.50 LSB	-55°C to +125°C	E-28A

*E = Leadless Ceramic Chip Carrier; J = Ceramic Leaded Chip Carrier; Q = Cerdip.

CAUTION _

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD9012 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



PIN FUNCTION DESCRIPTIONS

Pin #	Name	Description							
1 2	DIGITAL +V _S OVERFLOW INH	One of three positive digital supply pins (nominally +5.0 V). OVERFLOW INHIBIT controls the data output coding for overvoltage inputs (AIN \geq + V _{REF}).							
		ANALOG INPUT	OVERFLOW INHIBITED (GND) OF D ₁ D ₂ D ₃ D ₄ D ₅ D ₆ D ₇ D ₈						
		$\frac{V_{\rm IN} \geq + V_{\rm REF}}{V_{\rm IN} < + V_{\rm REF}}$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	0 1 1 1 1 1 1 1 1 1 0 X X X X X X X X X					
3	HYSTERESIS	The Hysterest change from -	is control voltage varies the comparator hyste -5.2 V to -2.2 V at the Hysteresis control pin	resis from 0 mV to 10 mV, for a					
4	+V _{REF}	The most pos	itive reference voltage for the internal resistor	r ladder.					
5	ANALOG INPUT	One of two ar	alog input pins. Both analog input pins shou	ld be connected together.					
6	ANALOG GROUND	One of two ar	alog ground pins. Both analog ground pins s	hould be connected together.					
7	ENCODE	TTL level end	TTL level encode command input. ENCODE is rising edge sensitive.						
8	DIGITAL +V _S	One of three positive digital supply pins (nominally $+5.0$ V).							
9	ANALOG GROUND	One of two analog ground pins. Both analog ground pins should be connected together.							
10	ANALOG INPUT	One of two analog input pins. Both analog inputs should be connected together.							
11	-V _{REF}	The most negative reference voltage for the internal resistor ladder.							
12	REF _{MID}	The midpoint tap on the internal resistor ladder.							
13	DIGITAL +V _S	One of three positive digital supply pins (nominally +5.0 V).							
14	DIGITAL –Vs	One of two negative digital supply pins (nominally -5.2 V). Both digital supply pins should be connected together.							
15	D_1 (LSB)	Digital data output. D_1 (LSB) is the least significant bit of the digital output word.							
16–19	D_2-D_5	Digital data output.							
20	DIGITAL GROUND	One of two digital ground pins. Both digital grounds pins should be connected together.							
21, 22	ANALOG –Vs	One of two negative analog supply pins (nominally -5.2 V). Both analog supply pins should be connected together.							
23	DIGITAL GROUND	One of two digital ground pins. Both digital ground pins should be connected together.							
24, 25	D_{6}, D_{7}	Digital data output.							
26	D_8 (MSB)	Digital data o	utput D_8 (MSB) is the most significant bit of	the digital output word.					
27	OVERFLOW	Overflow data output. Logic HIGH indicates an input overvoltage ($V_{IN} > + V_{REF}$), if OVERELOW INHIBIT is enabled (overflow enabled, floating). See OVERELOW INHIBIT							
28	DIGITAL –Vs	One of two negative digital supply pins (nominally -5.2 V). Both digital supply pins should be connected together.							

PIN CONFIGURATIONS





Figure 2. Timing Diagram





DIE LAYOUT AND MECHANICAL INFORMATION



Die Dimensions	$111 \times 123 \times 15 (\pm 2)$ mils
Pad Dimensions	$\dots \dots \dots \dots \dots 4 \times 4$ mils
Metalization	Gold
Backing	None
Substrate Potential	
Passivation	Nitride
Die Attach	Gold Eutectic (Ceramic)
	Epoxy (Plastic)
Bond Wire 1–1.3 mil	Gold; Gold Ball Bonding



Figure 4. Burn-In Diagram

APPLICATION INFORMATION

The AD9012 is compatible with all standard TTL logic families. However, to operate at the highest encode rates, the supporting logic around the AD9012 will need to be equally fast. Two possible choices are the AS and the ALS families. Whichever of the TTL logic families is used, special care must be exercised to keep digital switching noise away from the analog circuits around the AD9012. The two most critical items are the digital supply lines and the digital ground return.

The input capacitance of the AD9012 is an exceptionally low 16 pF. This allows the use of a wide range of input amplifiers, both hybrid and monolithic. To take full advantage of the 160 MHz input bandwidth of the AD9012, a hybrid amplifier like the AD9610/AD9611 will be required. For those applications that do not require the full input bandwidth of the AD9012, some of the more traditional monolithic amplifiers, like the AD846, should work very well. Overall performance with monolithic amplifiers can be improved by inserting a 40 Ω resistor in series with the amplifier output.

The output data is buffered through the TTL compatible output latches. In addition to the latch propagation delay (t_{PD}) , all data is delayed by one clock cycle, before becoming available at the outputs. Both the analog-to-digital conversion cycle and the data transfer to the output latches are triggered on the rising edge of the TTL-compatible ENCODE signal (see timing diagram).

The AD9012 also incorporates a HYSTERESIS control pin which provides from 0 mV to 10 mV of additional hysteresis in the comparator input stages. Adjustments in the HYSTERESIS control voltage may help to improve noise immunity and overall performance in harsh environments.

The OVERFLOW INHIBIT pin of the AD9012 determines how the converter handles overrange inputs (AIN \geq + V_{REF}). In the "enabled" state (floating at –5.2 V), the OVERFLOW output will be at logic HIGH and all other outputs will be at logic LOW for overrange inputs (return-to-zero operation). In the "inhibited" state (tied to ground), the OVERFLOW output will be at logic LOW for overrange inputs, and all other digital outputs will be at logic HIGH (nonreturn-to-zero operation).

The AD9012 provides outstanding error rate performance. This is due to tight control of comparator offset matching and a fault tolerant decoding stage. Additional improvements in error rate are possible through the addition of hysteresis (see HYSTER-ESIS control pin). This level of performance is extremely important in fault sensitive applications such as digital radio (QAM).

Dramatic improvements in comparator design and construction give the AD9012 excellent dynamic characteristics, namely SNR (signal-to-noise ratio). The 160 MHz input bandwidth and low error rate performance give the AD9012 an SNR of 47 dB with a 1.23 MHz input. High SNR performance is particularly important in broadcast video applications where signals may pass through the converter several times before the processing is complete. Pulse signature analysis, commonly performed in advanced radar receivers, is another area that is especially dependent on high quality dynamic performance.

LAYOUT SUGGESTIONS

Designs using the AD9012, like all high-speed devices, must follow a few basic layout rules to insure optimum performance. Essentially, these guidelines are meant to avoid many of the problems associated with high-speed designs. The first requirement is for a substantial ground plane around and under the AD9012. Separate ground plane areas for the digital and analog components may be useful, but the separate grounds should be connected together at the AD9012 to avoid the effects of "ground loop" currents.

The second area that requires an extra degree of attention involves the three reference inputs, $+V_{REF}$, REF_{MID}, and $-V_{REF}$. The $+V_{REF}$ input and the $-V_{REF}$ input should both be driven from a low impedance source (note that the $+V_{REF}$ input is typically tied to analog ground). A low drift amplifier should provide satisfactory results, even over an extended temperature range. Adjustments at the REF_{MID} input may be useful in improving the integral linearity by correcting any reference ladder skews.

The reference inputs should be adequately decoupled to ground through 0.1 μ F chip capacitors to limit the effects of system noise on conversion accuracy. The power supply pins must also be decoupled to ground to improve noise immunity; 0.1 μ F and 0.01 μ F chip capacitors should be very effective.

The analog input signal is brought into the AD9012 through two separate input pins. It is very important that the two input pins be driven symmetrically with equal length electrical connections. Otherwise, aperture delay errors may degrade converter performance at high frequencies.



Figure 5. Typical Application



Figure 6. Evaluation Circuit



Figure 7. Dynamic Performance

OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

